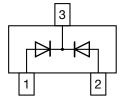


## Vishay Semiconductors

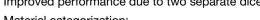
## RF PIN Diodes - Dual, Common Cathode in SOT-323





#### **FEATURES**

- · High voltage current controlled RF resistor
- Small diode capacitance
- · Low series inductance
- · Low forward resistance
- Improved performance due to two separate dice



• Material categorization: definitions compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION**

Characterized by low reverse capacitance the PIN diodes BAR64V-05W-V was designed for RF signal switching and tuning. As a function of the forward bias current the forward resistance (RF) can be adjusted over a wide range. A long carrier life time offers low signal distortion for signals over 10 MHz up to 3 GHz. Typical applications for these PIN diodes are switches and attenuators in wireless, mobile, and TV-systems.

#### **APPLICATIONS**

- For frequencies up to 3 GHz
- · RF-signal tuning
- · Signal attenuator and switches
- Mobile, wireless and TV-Applications

#### **MECHANICAL DATA**

Case: SOT-323

Weight: approx. 5.7 mg Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE TYPE MARKING INTERNAL CONSTRUCTION		REMARKS		
BAR64V-05W-V	BAR64V-05W-V-GS18 or BAR64V-05W-V-GS08	DW5	Dual common cathode	Tape and reel	

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PART	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	100	V	
Forward continuous current		I <sub>F</sub>	100	mA	

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL VALUE		UNIT	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	- 55 to + 150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA		$V_{F}$			1.1	V
Reverse voltage	$I_F = 10 \mu A$		$V_R$	100			V
Reverse current	V <sub>R</sub> = 50 V		I <sub>R</sub>			0.05	μΑ
Diode capacitance	f = 1 MHz, V <sub>R</sub> = 0 V		C <sub>D</sub>		0.5		pF
	f = 1 MHz, V <sub>R</sub> = 1 V		$C_D$		0.37	0.5	pF
	f = 1 MHz, V <sub>R</sub> = 20 V		C <sub>D</sub>		0.23	0.35	pF
Differential forward resistance	f = 100 MHz, I <sub>F</sub> = 1 mA		r <sub>f</sub>		10	20	Ω
	f = 100 MHz, I <sub>F</sub> = 10 mA		r <sub>f</sub>		2	3.8	Ω
	f = 100 MHz, I <sub>F</sub> = 100 mA		r <sub>f</sub>		0.8	1.35	Ω
Charge carrier lifetime	$I_F = 10 \text{ mA}, I_R = 6 \text{ mA}, I_R = 3 \text{ mA}$		t <sub>rr</sub>		1.8		μs
Series inductance			L <sub>S</sub>		1		nH

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

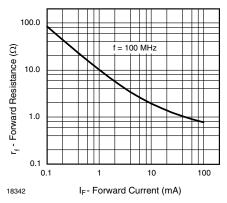


Fig. 1 - Forward Resistance vs. Forward Current

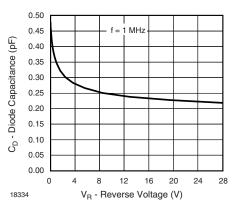


Fig. 2 - Diode Capacitance vs. Reverse Voltage

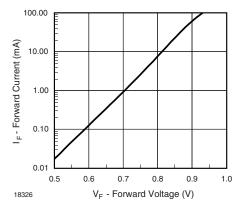


Fig. 3 - Forward Current vs. Forward Voltage

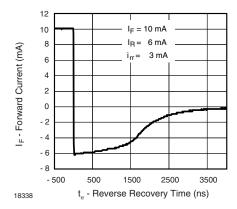


Fig. 4 - Typical Charge Recovery Curve



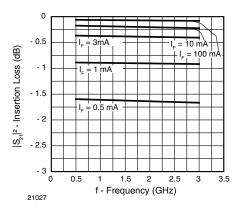


Fig. 5 - Insertion Loss of One Diode Inserted in Series with 50  $\Omega$   $\:$  Strip Line

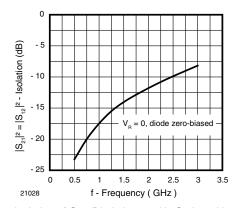


Fig. 6 - Isolation of One Diode Inserted in Series with 50  $\Omega$  Strip Line

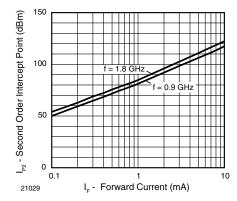
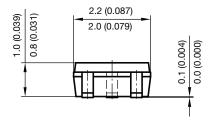


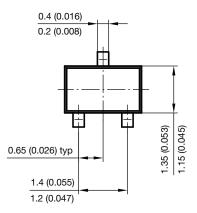
Fig. 7 - Second Order Intercept Point for One Diode Inserted in 50  $\Omega$  Strip Line



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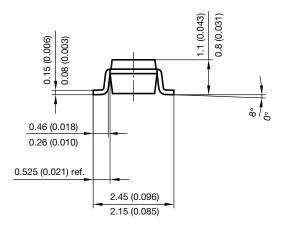
### PACKAGE DIMENSIONS in millimeters (inches): SOT-323



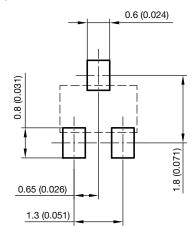


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foot print recommendation:



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